

In th Unit d Stat s Patent and Trademark Offic

al Number: NA

Appn. Filed: 06/30/2003 (by retunned receiving postcard)

Applicant: Hai Jiang

Appn. Title: FABRICATION OF ULTRA-SMALL MEMORY ELEMENTS

Mailed: 09/16/2003 At: Fremont, CA 94539

10/609,157

Information Disclosure Statement

Commissioner for Patent Washington, DC 20231

Sir:

Attached is a completed Forms PTO/SB/08(A&B) and copies of the pertinent parts of the references cited thereon.

Very respectively,

Applicant:

c/o: Hai Jiang

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I certify that this correspondence will be deposited with the United States Post Service as Certifical Priority Mail with proper postage affixed in an envelope addressed to "Commissioner for Patent, Washington, DC 20231" on the date below.

Date: 2003, Sept. 16, Hai Jiang

PTO/SB/08B (04-03)

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(Use as many sheets as necessary)			PPLICANT	First Named Inventor	Hai Jiang	
				Art Unit		
			ecessary)	Examiner Name		_
Sheet		of		Attorney Docket Number		

		NON PATENT LITERATURE DOCUMENTS	
Examiner Cite Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), titl the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-is number(s), publisher, city and/or country where published.			T ²
:	F	J. N. Zhou, etc, "Thickness dependence of magnetic percolation threhold in as-deposited	
		and annealed Fe-SiO2 graular very thin films", J. Appl. Phys. 84, (1998)5693	
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Sheet 1

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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of 2

Complete if Known					
Application Number					
Filing Date	06-30-2003				
First Named Inventor	Hai Jiang				
Art Unit					
Examiner Name					
Attorney Docket Number					

U. S. PATENT DOCUMENTS							
Examiner Initials*	Cite No.1	Document Number Number-Kind Code ^{2 (# known)}	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear		
	Α	^{US-} 5,825,046	10-20-1998	Wolodymyr Czubatyj			
	В	^{US-} US2003/0116794A	06-26-2003	Tyler A. Lowrey			
	С	^{US-} US2002/0123170A	09-05-2002	Johm T. Moore			
	D	^{US-} US2003/0146452A	08-07-2003	Chien Chiang			
	E	^{US-} 6,075,719	06-13-2000	Tyler Lowrey			
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FOREIGN PATENT DOCUMENTS							
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